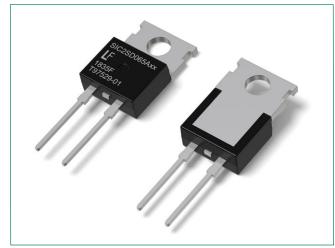
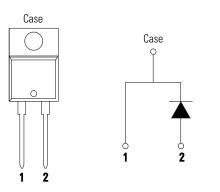
LSIC2SD065A08A 650 V, 8 A SiC Schottky Barrier Diode

HF Rohs 🕫



*Image for reference only, for details refer to Dimensions-Package.

Circuit Diagram TO-220-2L



Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations
- Uninterruptible power supplies

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo =**HF** Halogen Free
- Littelfuse "Pb-free" logo
 Pb-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	650	V	
DC Blocking Voltage	V _R	T _J = 25 °C	650	V	
Continuous Forward Current		T _c = 25 °C	23	A	
	I _F	T _c = 135 °C	10.7		
		T _c = 150 °C 8]	
Non-Repetitive Forward Surge Current	I _{FSM}	I_{FSM} $T_{c} = 25 \text{ °C}, T_{p} = 10 \text{ ms}, \text{ Half sine pulse}$		A	
Power Dissipation	P _{Tot}	$T_c = 25 \text{ °C}$	88	W	
		T _c = 110 °C	_c = 110 °C 38		
Operating Junction Temperature	T	-	-55 to 175	°C	
Storage Temperature	T _{stg}	-	-55 to 150	°C	
Soldering Temperature	T _{SOLD}	-	260	°C	

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GEN2 SiC Schottky Diode

LSIC2SD065A08A, 650V, 8A, TO-220-2L

Electrical	Characteristics	(Т	=25 °C unless otherwise specified)
LICOUITOUT	onaraotonotio		

Characteristics Syr	Symbol	Conditions	Value			Unit
Characteristics	Symbol	Conditions	Min.	Тур.	Max.	Onit
Forward Voltage		I _F = 8 A, T _J = 25 °C	-	1.5	1.8	V
	V _F	I _F = 8 A, T _J = 175 °C	-	1.85	-	V
Reverse Current I _R	1	$V_{_{ m R}} = 650 \text{ V}$, $T_{_{ m J}} = 25 \ ^{\circ}\text{C}$	-	<1	50	
	R	$V_{_{ m R}}$ = 650 V , $T_{_{ m J}}$ = 175 °C	-	15	-	μΑ
Total Capacitance C		$V_{_{\mathrm{R}}} = 1 \text{ V}, \text{ f} = 1 \text{ MHz}$	-	415	-	pF
	С	$V_{_{\mathrm{R}}} = 200 \text{ V}, \text{ f} = 1 \text{ MHz}$	-	56	-	
		$V_{_{ m R}} = 400 \text{ V}, \text{ f} = 1 \text{ MHz}$	-	41	-	
Total Capacitive Charge	Q _c	$V_{R} = 400 \text{ V}, Q_{c} = \int_{0}^{V_{R}} C(V) dV$	-	29	-	nC

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Characteristics	Symbol	Value	Unit
Thermal Resistance	R _{eJC}	1.7	°C/W

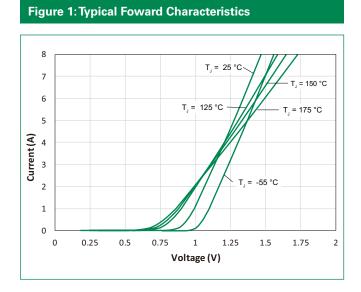
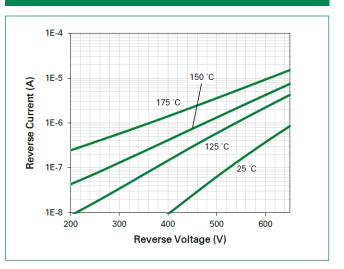


Figure 2: Typical Reverse Characteristics



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GEN2 SiC Schottky Diode LSIC2SD065A08A, 650V, 8A, TO-220-2L

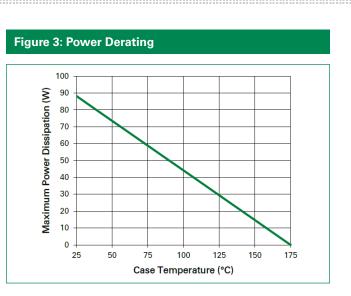


Figure 5: Capacitance vs. Reverse Voltage

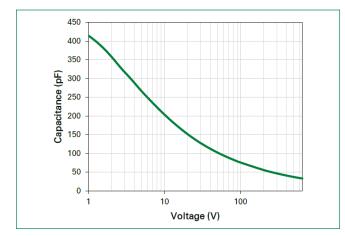


Figure 7: Stored Energy vs. Reverse Voltage

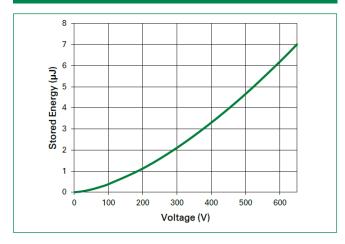


Figure 4: Current Derating

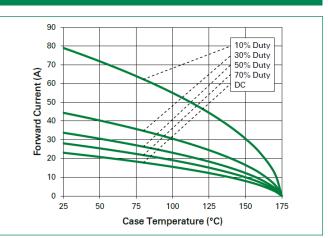


Figure 6: Capacitive Charge vs. Reverse Voltage

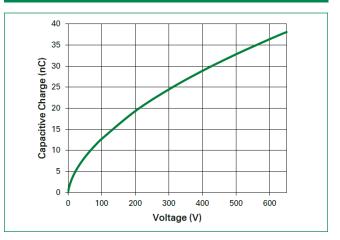
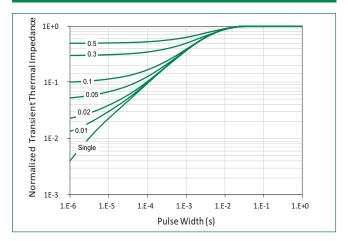


Figure 8: Transient Thermal Impedance



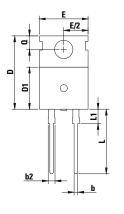
Littelfuse Power

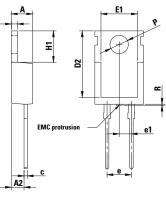
GEN2 SiC Schottky Diode

LSIC2SD065A08A, 650V, 8A, TO-220-2L

Dimensions-Package TO-220-2L

A1



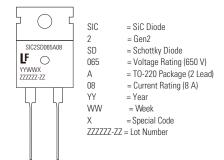


Recommended Hole Pattern



Ormalial	Millimeters				
Symbol	Min	Nom	Max		
Α	4.30	4.45	4.70		
A1	1.14	1.27	1.40		
A2	2.20	-	2.74		
b	0.69	-	0.90		
b2	1.17	-	1.62		
С	0.36	-	0.60		
D	14.90	-	15.90		
D1	8.62	-	9.40		
D2	12.50	-	12.95		
E	9.70	10.18	10.36		
E1	7.57	7.61	8.30		
e1	-	2.54	-		
е	5.03	5.08	5.13		
H1	6.30	6.55	6.80		
L	12.88	13.50	14.00		
L1	2.39	-	3.25		
øP	3.50	3.84	3.96		
Q	2.65	-	3.05		
R	-	-	0.25		

Part Numbering and Marking System



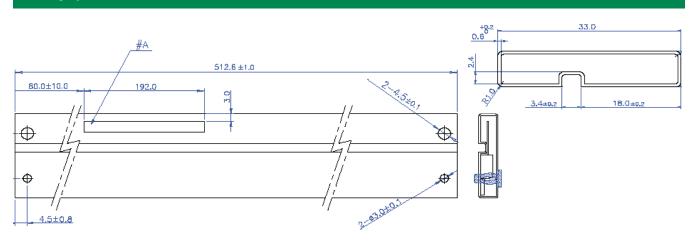
Packing Options

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065A08A	SIC2SD065A08	Tube(50pcs)	1000



GEN2 SiC Schottky Diode LSIC2SD065A08A, 650V, 8A, TO-220-2L

Packing Specification (Tube for TO-220-2L)



NOTE]

- TUBE - MATERIAL : PVC / PET (WITH ANTISTATIC COATING)
- COLOR : TRANSPARENCY, RED, YELLO
- MARKING #A : BLACK COLOR, LETTER STYLE : Arial
- Tube Surface Resistance $\div10^{6}{\sim}10^{11}\,\Omega\,/\,\text{square}$
- ESD (Electro Static Discharge) : less than 100 [volts], 6 Months
- CAMBAR : 1.5 MAX
- $\ensuremath{\mathsf{PIN}}$ COLOR : GREEN (ONE PIN MUST BE INSERTED IN LEFT-SIDE OF " $\ensuremath{\mathsf{-ANTISTATIC}}\xspace^{-1}$ and another PIN IS FREE.)

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